# **UJA1079**LIN core system basis chip

Rev. 01 — 1 December 2009

Product data sheet

# 1. General description

The UJA1079 core System Basis Chip (SBC) replaces the basic discrete components commonly found in Electronic Control Units (ECU) with a Local Interconnect Network (LIN) interface.

The UJA1079 supports the networking applications used to control power and sensor peripherals by using the LIN interface as a local sub-bus.

The core SBC contains the following integrated devices:

- LIN transceiver compliant with LIN 2.1, LIN 2.0 and SAE J2602, and compatible with LIN 1.3
- Advanced independent watchdog (UJA1079/xx/WD versions)
- 250 mA voltage regulator for supplying a microcontroller; extendable with external PNP transistor for increased current capability and dissipation distribution
- Serial peripheral interface (full duplex)
- · 2 local wake-up input ports
- Limp home output port

In addition to the advantages gained from integrating these common ECU functions in a single package, the core SBC offers an intelligent combination of system-specific functions such as:

- Advanced low-power concept
- Safe and controlled system start-up behavior
- Detailed status reporting on system and sub-system levels

The UJA1079 is designed to be used in combination with a microcontroller. The SBC ensures that the microcontroller always starts up in a controlled manner.



## 2. Features

#### 2.1 General

- Contains LIN ECU functions:
  - LIN transceiver
  - Scalable 3.3 V or 5 V voltage regulator delivering up to 250 mA for a microcontroller and peripheral circuitry; an external PNP transistor can be connected for better heat distribution over the PCB
  - Watchdog with Window and Timeout modes and on-chip oscillator
  - Serial Peripheral Interface (SPI) for communicating with the microcontroller
  - ◆ ECU power management system
- Designed for automotive applications:
  - ◆ Excellent ElectroMagnetic Compatibility (EMC) performance
  - ◆ ±8 kV ElectroStatic Discharge (ESD) protection Human Body Model (HBM) on the LIN bus pin and the WAKE pins
  - ◆ ±6 kV ElectroStatic Discharge (ESD) protection IEC 61000-4-2 on the LIN bus pin
    and the WAKE pins
  - ◆ ±58 V short-circuit proof LIN bus pin
  - Battery and LIN bus pins are protected against transients in accordance with ISO 7637-3
- Small 6.1 mm × 11 mm HTSSOP32 package with low thermal resistance
- Pb-free; RoHS and dark green compliant

#### 2.2 LIN transceiver

- LIN 2.1 compliant LIN transceiver
- Compliant with SAE J2602
- Downward compatible with LIN 2.0 and LIN 1.3
- Low slope mode for optimized EMC performance
- Integrated LIN termination diode at pin DLIN

#### 2.3 Power management

- Wake-up via LIN or local WAKE pins with wake-up source detection
- 2 WAKE pins:
  - WAKE1 and WAKE2 inputs can be switched off to reduce current flow
  - Output signal (WBIAS) to bias the WAKE pins, selectable sampling time of 16 ms or 64 ms
- Standby mode with very low standby current and full wake-up capability; V1 active to maintain supply to the microcontroller
- Sleep mode with very low sleep current and full wake-up capability

## 2.4 Control and Diagnostic features

- Safe and predictable behavior under all conditions
- Programmable watchdog with independent clock source

www.DataSheet4U.com

UJA1079\_1 © NXP B.V. 2009. All rights reserved

- Window, Timeout (with optional cyclic wake-up) and Off modes supported (with automatic re-enable in the event of an interrupt)
- 16-bit Serial Peripheral Interface (SPI) for configuration, control and diagnosis
- Global enable output for controlling safety-critical hardware
- Limp home output (LIMP) for activating application-specific 'limp home' hardware in the event of a serious system malfunction
- Overtemperature shutdown
- Interrupt output pin; interrupts can be individually configured to signal V1 undervoltage,
   LIN/local wake-up and cyclic and power-on interrupt events
- Bidirectional reset pin with variable power-on reset length to support a variety of microcontrollers
- Software-initiated system reset

# 2.5 Voltage regulator V1

- Scalable voltage regulator for the microcontroller, its peripherals and additional external transceivers
- ±2 % accuracy for LIN master application
- ±3 % accuracy for LIN slave application
- 3.3 V and 5 V versions available
- Delivers up to 250 mA and can be combined with an external PNP transistor for better heat distribution over the PCB
- Selectable current threshold at which the external PNP transistor starts to deliver current
- Undervoltage warning at 90 % of nominal output voltage and undervoltage reset at 90 % or 70 % of nominal output voltage
- Can operate at V<sub>BAT</sub> voltages down to 4.5 V (e.g. during cranking), in accordance with ISO7637 pulse 4/4b and ISO16750-2
- Stable output under all conditions

www.DataSheet4U.com

# 3. Ordering information

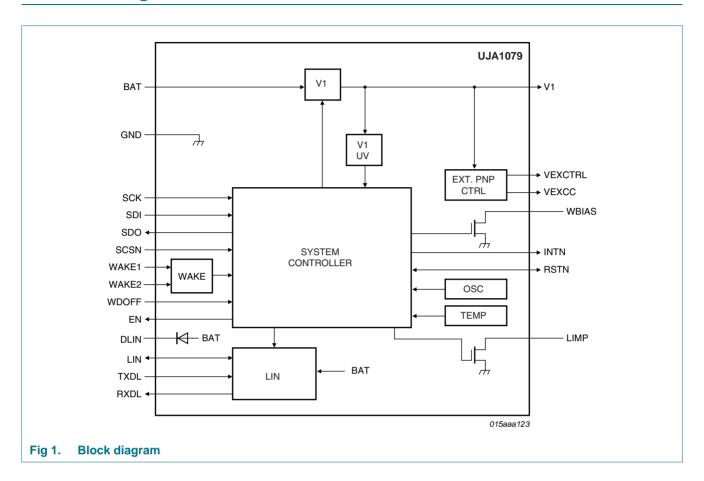
Table 1. Ordering information

Type number	Package						
	Name	Name Description					
UJA1079TW/5V0/WD	HTSSOP32	- · · -					
UJA1079TW/3V3/WD		leads; body width 6.1 mm; lead pitch 0.65 mm; exposed die pa					
UJA1079TW/5V0							
UJA1079TW/3V3							

<sup>[1]</sup> UJA1079TW/5V0xx versions contain a 5 V regulator (V1); UJA1079TW/3V3xx versions contain a 3.3 V regulator (V1); WD versions contain a watchdog.

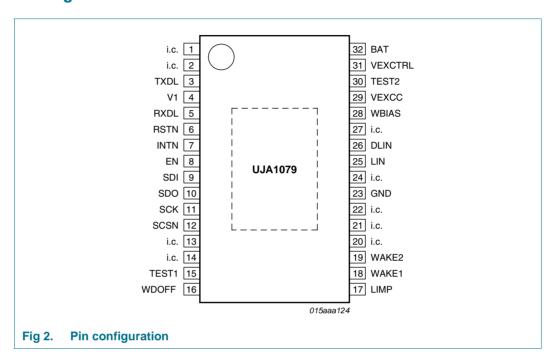
UJA1079\_1 © NXP B.V. 2009. All rights reserved.

# 4. Block diagram



# 5. Pinning information

# 5.1 Pinning



# 5.2 Pin description

Table 2. Pin description

www. Data Sheet 4U.com

Table 2.	Pin desc	scription				
Symbol	Pin	Description				
i.c.	1	internally connected; should be left floating				
i.c.	2	internally connected; should be left floating				
TXDL	3	LIN transmit data input				
V1	4	voltage regulator output for the microcontroller (5 V or 3.3 V depending on SBC version)				
RXDL	5	LIN receive data output				
RSTN	6	reset input/output to and from the microcontroller				
INTN	7	interrupt output to the microcontroller				
EN	8	enable output				
SDI	9	SPI data input				
SDO	10	SPI data output				
SCK	11	SPI clock input				
SCSN	12	SPI chip select input				
i.c.	13	internally connected; should be left floating				
i.c.	14	internally connected; should be left floating				
TEST1	15	test pin; pin should be connected to ground				
WDOFF	16	WDOFF pin for deactivating the watchdog				
LIMP	17	limp home output				

Table 2. Pin description ...continued

Symbol	Pin	Description
WAKE1	18	local wake-up input 1
WAKE2	19	local wake-up input 2
i.c.	20	internally connected; should be left floating
i.c.	21	internally connected; should be left floating
i.c.	22	internally connected; should be left floating
GND	23	ground
i.c.	24	internally connected; should be left floating
LIN	25	LIN bus line
DLIN	26	LIN termination resistor connection
i.c.	27	internally connected; should be left floating
WBIAS	28	control pin for external wake biasing transistor
VEXCC	29	current measurement for external PNP transistor; this pin is connected to the collector of the external PNP transistor
TEST2	30	test pin; pin should be connected to ground
VEXCTRL	31	control pin of the external PNP transistor; this pin is connected to the base of the external PNP transistor
BAT	32	battery supply for the SBC

The exposed die pad at the bottom of the package allows for better heat dissipation from the SBC via the printed circuit board. The exposed die pad is not connected to any active part of the IC and can be left floating, or can be connected to GND.

# 6. Functional description

www.DataSheet4U.com

The UJA1079 combines the functionality of a LIN transceiver, a voltage regulator and a watchdog (UJA1079/xx/WD versions) in a single, dedicated chip. It handles the power-up and power-down functionality of the ECU and ensures advanced system reliability. The SBC offers wake-up by bus activity, by cyclic wake-up and by the activation of external switches. Additionally, it provides a periodic control signal for pulsed testing of wake-up switches, allowing low-current operation even when the wake-up switches are closed in Standby mode.

The LIN transceiver is optimized to be highly flexible with regard to bus topologies.

V1, the voltage regulator, is designed to power the ECU's microcontroller, its peripherals and additional external transceivers. An external PNP transistor can be added to improve heat distribution. The watchdog is clocked directly by the on-chip oscillator and can be operated in Window, Timeout and Off modes.

# 6.1 System Controller

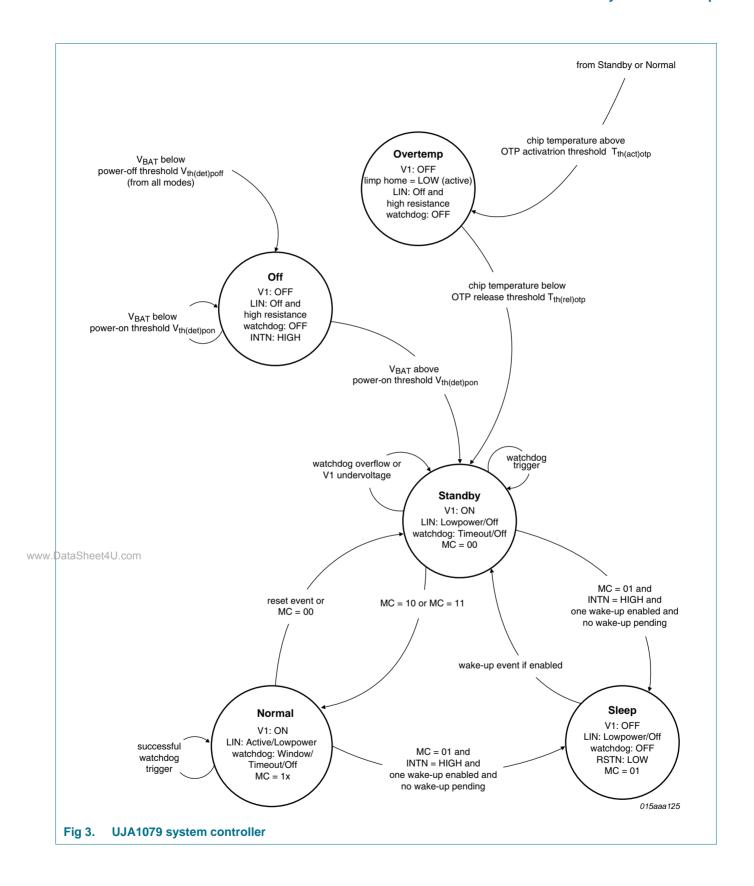
#### 6.1.1 Introduction

The system controller manages register configuration and controls the internal functions of the SBC. Detailed device status information is collected and presented to the microcontroller. The system controller also provides the reset and interrupt signals.



The system controller is a state machine. The SBC operating modes, and how transitions between modes are triggered, are illustrated in <u>Figure 3</u>. These modes are discussed in more detail in the following sections.





#### 6.1.2 Off mode

The SBC switches to Off mode from all other modes if the battery supply drops below the power-off detection threshold ( $V_{th(det)poff}$ ). In Off mode, the voltage regulator is disabled and the bus system is in a high-resistive state.

As soon as the battery supply rises above the power-on detection threshold ( $V_{th(det)pon}$ ), the SBC goes to Standby mode, and a system reset is executed (reset pulse width of  $t_{w(rst)}$ , long or short; see Section 6.5.1 and Table 10).

## 6.1.3 Standby mode

The SBC will enter Standby mode:

- From Off mode if V<sub>BAT</sub> rises above the power-on detection threshold (V<sub>th(det)pon</sub>)
- From Sleep mode on the occurrence of a LIN or local wake-up event
- From Overtemp mode if the chip temperature drops below the overtemperature protection release threshold, T<sub>th/rel)oto</sub>
- From Normal mode if bit MC is set to 00 or a system reset is performed (see Section 6.5)

In Standby mode, V1 is switched on. The LIN transceiver will either be in a low-power state (Lowpower mode; STBCL = 1; see <u>Table 6</u>) with bus wake-up detection enabled or completely switched off (Off mode; STBCL = 0) - see <u>Section 6.7.1</u>. The watchdog can be running in Timeout mode or Off mode, depending on the state of the WDOFF pin and the setting of the watchdog mode control bit (WMC) in the WD\_and\_Status register (<u>Table 4</u>).

The SBC will exit Standby mode if:

- Normal mode is selected by setting bits MC to 10 or 11
- Sleep mode is selected by setting bits MC to 01
- The chip temperature rises above the OTP activation threshold, T<sub>th(act)otp</sub>, causing the SBC to enter Overtemp mode

#### 6.1.4 Normal mode

Normal mode is selected from Standby mode by setting bits MC in the Mode\_Control register (Table 5) to 10 or 11.

In Normal mode, the LIN physical layer (LIN) will be enabled (Active mode; STBCL = 0; see <u>Table 6</u>) or in a low-power state (Lowpower mode; STBCL = 1) with bus wake-up detection active.

The SBC will exit Normal mode if:

- Standby mode is selected by setting bits MC to 00
- Sleep mode is selected by setting bits MC to 01
- A system reset is generated (see <u>Section 6.1.3</u>; the SBC will enter Standby mode)
- The chip temperature rises above the OTP activation threshold, T<sub>th(act)otp</sub>, causing the SBC to switch to Overtemp mode

www.DataSheet4U.com

UJA1079\_1 © NXP B.V. 2009. All rights reserved.

#### 6.1.5 Sleep mode

Sleep mode is selected from Standby mode or Normal mode by setting bits MC in the Mode\_Control register (<u>Table 5</u>) to 01. The SBC will enter Sleep mode providing there are no pending interrupts (INTN = HIGH) or wake-up events and at least one wake-up source is enabled (LIN or WAKE). Any attempt to enter Sleep mode while one of these conditions has not been satisfied will result in a short reset (3.6 ms min. pulse width; see <u>Section 6.5.1</u> and <u>Table 10</u>).

In Sleep mode, V1 is off and the LIN transceiver will be switched off (Off mode; STBCL = 0; see  $\underline{\text{Table 6}}$ ) or in a low-power state (Lowpower mode; STBCL = 1) with bus wake-up detection active - see  $\underline{\text{Section 6.7.1}}$ ). The watchdog is off and the reset pin is LOW.

A LIN or local wake-up event will cause the SBC to switch from Sleep mode to Standby mode, generating a (short or long; see Section 6.5.1) system reset. The value of the mode control bits (MC) will be changed to 00 and V1 will be enabled.

## 6.1.6 Overtemp mode

The SBC will enter Overtemp mode from Normal mode or Standby mode when the chip temperature exceeds the overtemperature protection activation threshold,  $T_{th(act)otp}$ ,

In Overtemp mode, the voltage regulator is switched off and the bus system is in a high-resistive state. When the SBC enters Overtemp mode, the RSTN pin is driven LOW and the limp home control bit, LHC, is set so that the LIMP pin is driven LOW.

The chip temperature must drop a hysteresis level below the overtemperature shutdown threshold before the SBC can exit Overtemp mode. After leaving Overtemp mode the SBC enters Standby mode and a system reset is generated (reset pulse width of  $t_{w(rst)}$ , long or short; see Section 6.5.1 and Table 10).

#### 6.2 SPI

www.DataSheet4U.com

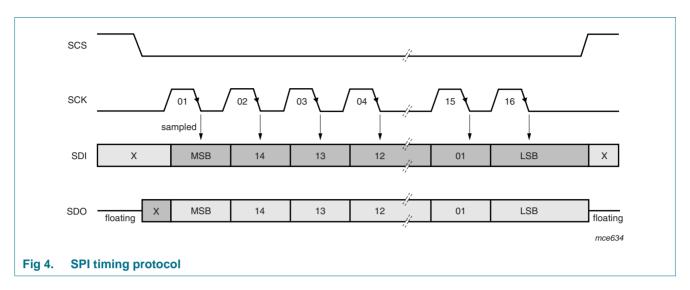
#### 6.2.1 Introduction

The Serial Peripheral Interface (SPI) provides the communication link with the microcontroller, supporting multi-slave operations. The SPI is configured for full duplex data transfer, so status information is returned when new control data is shifted in. The interface also offers a read-only access option, allowing registers to be read back by the application without changing the register content.

The SPI uses four interface signals for synchronization and data transfer:

- SCSN SPI chip select; active LOW
- SCK SPI clock; default level is LOW due to low-power concept
- SDI SPI data input
- SDO SPI data output; floating when pin SCSN is HIGH

Bit sampling is performed on the falling clock edge and data is shifted on the rising clock edge (see Figure 4).



# 6.2.2 Register map

The first three bits (A2, A1 and A0) of the message header define the register address. The fourth bit (RO) defines the selected register as read/write or read only.

Table 3. Register map

Address bits 15, 14 and 13	Write access bit 12 = 0	Read/Write access bits 11 0
000	0 = read/write, 1 = read only	WD_and_Status register
001	0 = read/write, 1 = read only	Mode_Control register
010	0 = read/write, 1 = read only	Int_Control register
011	0 = read/write, 1 = read only	Int_Status register



# 6.2.3 WD\_and\_Status register

Table 4. WD\_and\_Status register

Bit	Symbol	Access	Power-on default	Description
15:13	A2, A1, A0	R	000	register address
12	RO	R/W	0	access status
				0: register set to read/write
				1: register set to read only
11	WMC	R/W	0	watchdog mode control
				0: Normal mode: watchdog in Window mode; Standby mode: watchdog in Timeout mode
				1: Normal mode: watchdog in Timeout mode; Standby mode: watchdog in O mode
10:8	NWP[1]	R/W	100	nominal watchdog period
				000: 8 ms
				001: 16 ms
				010: 32 ms
				011: 64 ms
				100: 128 ms
				101: 256 ms
				110: 1024 ms
				111: 4096 ms
7	SWR/WOS	R/W	-	software reset/watchdog off status
				0: WDOFF pin LOW; watchdog mode determined by bit WMC
				1: watchdog disabled due to HIGH level on pin WDOFF; results in software reset
D <b>6</b> ataShe	eeV4S.com	R	-	V1 status
				0: V1 output voltage above 90 % undervoltage recovery threshold ( $V_{uvr}$ ; see Table 9)
				1: V1 output voltage below 90 % undervoltage detection threshold ( $V_{uvd}$ ; se Table 9)
5	reserved	R	1	
4	WLS1	R	-	wake-up1 status
				0: WAKE1 input voltage below switching threshold $(V_{th(sw)})$
				1: WAKE1 input voltage above switching threshold (V <sub>th(sw)</sub> )
3	WLS2	R	-	wake-up 2 status
				0: WAKE2 input voltage below switching threshold $(V_{th(sw)})$
				1: WAKE2 input voltage above switching threshold $(V_{th(sw)})$
2:0	reserved	R	000	

<sup>[1]</sup> Bit NWP is set to it's default value (100) after a reset.



# 6.2.4 Mode\_Control register

Table 5. Mode\_Control register

Bit	Symbol	Access	Power-on default	Description
15:13	A2, A1, A0	R	001	register address
12	RO	R/W	0	access status
				0: register set to read/write
				1: register set to read only
11:10	MC	R/W	00	mode control
				00: Standby mode
				01: Sleep mode
				10: Normal mode
				11: Normal mode
9	LHWC[1]	_HWC[1] R/W 1		limp home warning control
				0: no limp home warning
				1: limp home warning is set; next reset will activate LIMP output
8 LHC <sup>2</sup> R/V		R/W	0	limp home control
				0: LIMP pin set floating
				1: LIMP pin driven LOW
7	ENC R/W		W 0	enable control
				0: EN pin driven LOW
				1: EN pin driven HIGH in Normal mode
6	LSC	R/W	0	LIN slope control
				0: normal slope, 20 kbit/s
				1: low slope, 10.4 kbit/s
5 DataShee	WBC et4U.com	R/W	0	wake bias control
				0: WBIAS floating if WSEn = 0; 16 ms sampling if WSEn = 1
				1: WBIAS on if WSEn = 0; 64 ms sampling if WSEn = 1
4	PDC	R/W	0	power distribution control
				0: V1 threshold current for activating the external PNP transistor; load currer rising; I <sub>th(act)PNP</sub> = 85 mA; V1 threshold current for deactivating the external PNP transistor; load current falling; I <sub>th(deact)PNP</sub> = 50 mA; see Figure 7
				1: V1 threshold current for activating the external PNP transistor; load currer rising; I <sub>th(act)PNP</sub> = 50 mA; V1 threshold current for deactivating the external PNP transistor; load current falling; I <sub>th(deact)PNP</sub> = 15 mA; see Figure 7
3:0	reserved	R	0000	

<sup>[1]</sup> Bit LHWC is set to 1 after a reset.

<sup>[2]</sup> Bit LHC is set to 1 after a reset, if LHWC was set to 1 prior to the reset.



# 6.2.5 Int\_Control register

Table 6. Int Control register

Bit	Symbol	Access	Power-on default	Description
15:13	A2, A1, A0	R	010	register address
12	RO	R/W	0	access status
				0: register set to read/write
				1: register set to read only
11	V1UIE	R/W	0	V1 undervoltage interrupt enable
				0: V1 undervoltage warning interrupts cannot be requested
				1: V1 undervoltage warning interrupts can be requested
10	reserved	R	0	
9	STBCL	R/W	0	LIN standby control
				0: When the SBC is in Normal mode (MC = 1x):
				LIN is in Active mode. The wake-up flag (visible on RXDL) is cleared regardless of the value of $V_{\text{BAT}}$ .
				When the SBC is in Standby/Sleep mode (MC = $0x$ ):
				LIN is in Off mode. Bus wake-up detection is disabled. LIN wake-up interrupts cannot be requested.
				1: LIN is in Lowpower mode with bus wake-up detection enabled, regardle of the SBC mode (MC = xx). LIN wake-up interrupts can be requested.
8	reserved	R	0	
7:6	WIC1	R/W	00	wake-up interrupt 1 control
				00: wake-up interrupt 1 disabled
				01: wake-up interrupt 1 on rising edge
				10: wake-up interrupt 1 on falling edge
DataShee	et4U.com			11: wake-up interrupt 1 on both edges
5:4	WIC2	R/W	00	wake-up interrupt 2 control
				00: wake-up interrupt 2 disabled
				01: wake-up interrupt 2 on rising edge
				10: wake-up interrupt 2 on falling edge
				11: wake-up interrupt 2 on both edges
3	reserved	R	0	
2	RTHC	R/W	0	reset threshold control
				0: The reset threshold is set to the 90 % V1 undervoltage detection voltage ( $V_{uvd}$ ; see <u>Table 9</u> )
				1: The reset threshold is set to the 70 % V1 undervoltage detection voltage ( $V_{uvd}$ ; see Table 9)
1	WSE1	R/W	0	WAKE1 sample enable
				0: sampling continuously
				1: sampling of WAKE1 is synchronized with WBIAS (sample rate controlled by WBC)



Table 6. Int\_Control register

Bit	Symbol	Access	Power-on default	Description
0	WSE2	R/W	0	WAKE2 sample enable
				0: sampling continuously
				1: sampling of WAKE1 is synchronized with WBIAS (sample rate controlled by WBC)

# 6.2.6 Int\_Status register

# Table 7. Int\_Status register[1]

Bit	Symbol	Access	Power-on default	Description
15:13	A2, A1, A0	R	011	register address
12	RO	R/W	0	access status
				0: register set to read/write
				1: register set to read only
11	V1UI	R/W	0	V1 undervoltage interrupts
				0: no V1 undervoltage warning interrupt pending
				1: V1 undervoltage warning interrupt pending
10	reserved	R	0	
9	LWI	R/W	0	LIN wake-up interrupt
				0: no LIN wake-up interrupt pending
				1: LIN wake-up interrupt pending
8	reserved	R	0	
7	CI	R/W	0	cyclic interrupt
				0: no cyclic interrupt pending
)ataShee	et4U.com			1: cyclic interrupt pending
6	WI1	R/W	0	wake-up interrupt 1
				0: no wake-up interrupt 1 pending
				1: wake-up interrupt 1 pending
5	POSI	R/W	1	power-on status interrupt
				0: no power-on interrupt pending
				1: power-on interrupt pending
4	WI2	R/W	0	wake-up interrupt 2
				0: no wake-up interrupt 2 pending
				1: wake-up interrupt 2 pending
3:0	reserved	R	0000	

<sup>[1]</sup> An interrupt can be cleared by writing 1 to the relevant bit in the Int\_Status register.

## 6.3 On-chip oscillator

The on-chip oscillator provides the timing reference for the on-chip watchdog and the internal timers. The on-chip oscillator is supplied by an internal supply that is connected to  $V_{BAT}$  and is independent of V1.

## 6.4 Watchdog (UJA1079/xx/WD versions)

Three watchdog modes are supported: Window, Timeout and Off. The watchdog period is programmed via the NWP control bits in the WD\_and\_Status register (see <u>Table 4</u>). The default watchdog period is 128 ms.

A watchdog trigger event is any write access to the WD\_and\_Status register. When the watchdog is triggered, the watchdog timer is reset.

In watchdog Window mode, a watchdog trigger event within a closed watchdog window (i.e. the first half of the window before  $t_{trig(wd)1}$ ) will generate an SBC reset. If the watchdog is triggered before the watchdog timer overflows in Timeout or Window mode, or within the open watchdog window (after  $t_{trig(wd)1}$  but before  $t_{trig(wd)2}$ ), the timer restarts immediately.

The following watchdog events result in an immediate system reset:

- · the watchdog overflows in Window mode
- the watchdog is triggered in the first half of the watchdog period in Window mode
- the watchdog overflows in Timeout mode while a cyclic interrupt (CI) is pending
- the state of the WDOFF pin changes in Normal mode or Standby mode
- the watchdog mode control bit (WMC) changes state in Normal mode

After a watchdog reset (short reset; see Section 6.5.1 and Table 10), the default watchdog period is selected (NWP = 100). The watchdog can be switched off completely by forcing pin WDOFF HIGH. The watchdog can also be switched off by setting bit WMC to 1 in Standby mode. If the watchdog was turned off by setting WMC, any pending interrupt will re-enable it.

Note that the state of bit WMC cannot be changed in Standby mode if an interrupt is pending. Any attempt to change WMC when an interrupt is pending will be ignored.

#### 6.4.1 Watchdog Window behavior

The watchdog runs continuously in Window mode.

If the watchdog overflows, or is triggered in the first half of the watchdog period (less than  $t_{trig(wd)1}$  after the start of the watchdog period), a system reset will be performed. Watchdog overflow occurs if the watchdog is not triggered within  $t_{trig(wd)2}$  after the start of watchdog period.

If the watchdog is triggered in the second half of the watchdog period (at least  $t_{trig(wd)1}$ , but not more than  $t_{trig(wd)2}$ , after the start of the watchdog period), the watchdog will be reset.

The watchdog is in Window mode when pin WDOFF is LOW, the SBC is in Normal mode and the watchdog mode control bit (WMC) is set to 0.

#### 6.4.2 Watchdog Timeout behavior

The watchdog runs continuously in Timeout mode. It can be reset at any time by a watchdog trigger. If the watchdog overflows, the cyclic interrupt (CI) bit is set. If a CI is already pending, a system reset is performed.

The watchdog is in Timeout mode when pin WDOFF is LOW and:

- the SBC is in Standby mode and bit WMC = 0 or
- the SBC is in Normal mode and bit WMC = 1

#### 6.4.3 Watchdog Off behavior

The watchdog is disabled in this state.

The watchdog is in Off mode when:

- the SBC is in Off, Overtemp or Sleep modes
- the SBC is in Standby mode and bit WMC = 1
- the SBC is in any mode and the WDOFF pin is HIGH

## 6.5 System reset

The following events will cause the SBC to perform a system reset:

- V1 undervoltage (reset pulse length selected via external pull-up resistor on RSTN pin)
- An external reset (RSTN forced LOW)
- Watchdog overflow (Window mode)
- Watchdog overflow in Timeout mode with cyclic interrupt (CI) pending
- Watchdog triggered too early in Window mode
- WMC value changed in Normal mode
- WDOFF pin state changed
- SBC goes to Sleep mode (MC set to 01; see Table 5) while INTN is driven LOW
- SBC goes to Sleep mode (MC set to 01; see <u>Table 5</u>) while STBCL = WIC1 = WIC2 = 0
- SBC goes to Sleep mode (MC set to 01; see Table 5) while wake-up pending
- Software reset (SWR = 1)
- SBC leaves Overtemp mode (reset pulse length selected via external pull-up resistor on RSTN pin)

A watchdog overflow in Timeout mode requests a cyclic interrupt (CI), if a CI is not already pending.

The UJA1079 provides three signals for dealing with reset events:

- RSTN input/output for performing a global ECU system reset or forcing an external reset
- EN pin, a fail-safe global enable output
- LIMP pin, a fail-safe limp home output

www.DataSheet4U.com

© NXP B.V. 2009. All rights reserved.

UJA1079 1

## **6.5.1 RSTN pin**

A system reset is triggered if the bidirectional RSTN pin is forced LOW for at least  $t_{\text{fltr}}$  by the microcontroller (external reset). A reset pulse is output on RSTN by the SBC when a system reset is triggered internally.

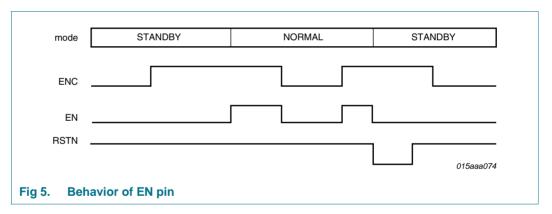
The reset pulse width  $(t_{w(rst)})$  is selectable (short or long) if the system reset was generated by a V1 undervoltage event (see <u>Section 6.6.2</u>) or by the SBC leaving Off  $(V_{BAT} > V_{th(det)pon})$  or Overtemp (temperature  $< T_{th(rel)otp})$  modes. A short reset pulse is selected by connecting a 900  $\Omega \pm 10$  % resistor between pins RSTN and V1. If a resistor is not connected, the reset pulse will be long (see <u>Table 10</u>).

In all other cases (e.g. watchdog-related reset events) the reset pulse length will be short.

#### 6.5.2 EN output

The EN pin can be used to control external hardware, such as power components, or as a general-purpose output when the system is running properly.

In Normal and Standby modes, the microcontroller can set the EN control bit (bit ENC in the Mode\_Control register; see  $\underline{\text{Table 5}}$ ) via the SPI interface. Pin EN will be HIGH when ENC = 1 and MC = 10 or 11. A reset event will cause pin EN to go LOW. EN pin behavior is illustrated in Figure 5.



www.DataSheet4U.com

## 6.5.3 LIMP output

The LIMP pin can be used to enable the so called 'limp home' hardware in the event of an ECU failure. Detectable failure conditions include SBC overtemperature events, loss of watchdog service, RSTN or V1 clamped LOW and user-initiated or external reset events.

The LIMP pin is a battery-related, active-LOW, open-drain output.

A system reset will cause the limp home warning control bit (bit LHWC in the Mode\_Control register; see <u>Table 5</u>) to be set. If LHWC is already set when the system reset is generated, bit LHC will be set which will force the LIMP pin LOW. The application should clear LHWC after each reset event to ensure the LIMP output is not activated during normal operation.

In Overtemp mode, bit LHC is always set and, consequently, the LIMP output is always active. If the application manages to recover from the event that activated the LIMP output, LHC can be cleared to deactivate the LIMP output.

## 6.6 Power supplies

## 6.6.1 Battery pin (BAT)

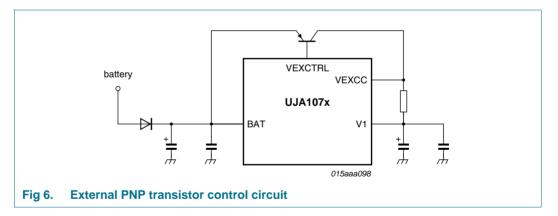
The SBC contains a single supply pin, BAT. An external diode is needed in series to protect the device against negative voltages. The operating range is from 4.5 V to 28 V. The SBC can handle maximum voltages up to 40 V.

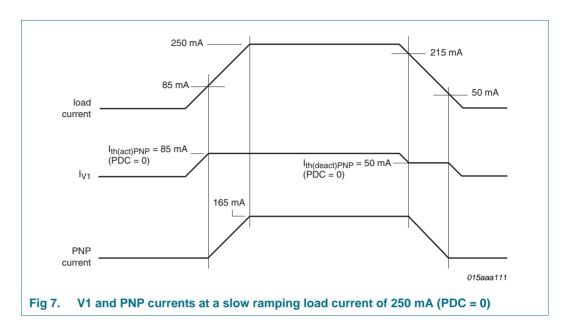
If the voltage on pin BAT falls below the power-off detection threshold,  $V_{th(det)poff}$ , the SBC immediately enters Off mode, which means that the voltage regulator and the internal logic are shut down. The SBC leaves Off mode for Standby mode as soon as the voltage rises above the power-on detection threshold,  $V_{th(det)pon}$ . The POSI bit in the Int\_Status register is set to 1 when the SBC leaves Off mode.

## 6.6.2 Voltage regulator V1

Voltage regulator V1 is intended to supply the microcontroller, its periphery and additional transceivers. V1 is supplied by pin BAT and delivers up to 250 mA at 3.3 V or 5 V (depending on the UJA1079 version).

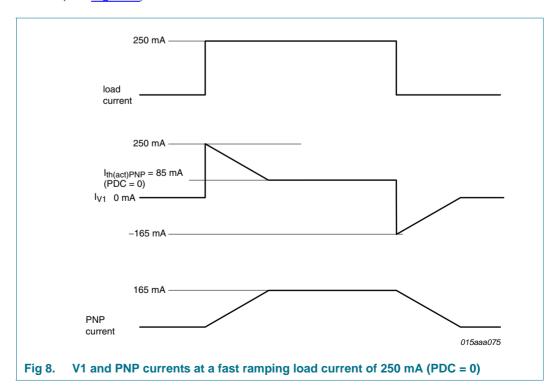
To prevent the device overheating at high ambient temperatures or high average currents, an external PNP transistor can be connected as illustrated in <u>Figure 6</u>. In this configuration, the power dissipation is distributed between the SBC and the PNP transistor. Bit PDC in the Mode\_Control register (<u>Table 5</u>) is used to regulate how the power dissipation is distributed – if PDC = 0, the PNP transistor will be activated when the load current reaches 85 mA (50 mA if PDC = 1) at  $T_{vj}$  = 150 °C. V1 will continue to deliver 85 mA while the transistor delivers the additional load current (see <u>Figure 7</u> and <u>Figure 8</u>).





<u>Figure 7</u> illustrates how V1 and the PNP transistor combine to supply a slow ramping load current of 250 mA with PDC = 0. Any additional load current requirement will be supplied by the PNP transistor, up to its current limit. If the load current continues to rise,  $I_{V1}$  will increase above the selected PDC threshold (to a maximum of 250 mA).

For a fast ramping load current, V1 will deliver the required load current (to a maximum of 250 mA) until the PNP transistor has switched on. Once the transistor has been activated, V1 will deliver 85 mA (PDC = 0) with the transistor contributing the balance of the load current (see Figure 8).



For short-circuit protection, a resistor needs to be connected between pins V1 and VEXCC to allow the current to be monitored. This resistor limits the current delivered by the external transistor. If the voltage difference between pins VEXCC and V1 reaches  $V_{th(act)llim}$ , the PNP current limiting activation threshold voltage, the transistor current will not increase further.

The thermal performance of the transistor needs to be considered when calculating the value of this resistor. A 3.3  $\Omega$  resistor was used with the BCP52-16 (NXP Semiconductors) employed during testing. Note that the selection of the transistor is not critical. In general, any PNP transistor with a current amplification factor ( $\beta$ ) of between 60 and 500 can be used.

If an external PNP transistor is not used, pin VEXCC must be connected to V1 while pin VEXCTRL can be left open.

One advantage of this scalable voltage regulator concept is that there are no PCB layout restrictions when using the external PNP. The distance between the UJA1079 and the external PNP doesn't affect the stability of the regulator loop because the loop is realized within the UJA1079. Therefore, it is recommended that the distance between the UJA1079 and PNP transistor be maximized for optimal thermal distribution.

The output voltage on V1 is monitored continuously and a system reset signal is generated if an undervoltage event occurs. A system reset is generated if the voltage on V1 falls below the undervoltage detection voltage (V<sub>uvd</sub>; see <u>Table 9</u>). The reset threshold (90 % or 70 % of the nominal value) is set via the Reset Threshold Control bit (RTHC) in the Int\_Control register (<u>Table 6</u>). In addition, an undervoltage warning (a V1UI interrupt) will be generated at 90 % of the nominal output voltage. The status of V1 can be read via bit V1S in the WD\_and\_Status register (<u>Table 4</u>).

# 6.7 LIN transceiver

www.DataSheet4U.com

The analog section of the UJA1079 LIN transceiver is identical to that integrated into the TJA1021.

The transceiver is the interface between the LIN master/slave protocol controller and the physical bus in a LIN. It is primarily intended for in-vehicle sub-networks using baud rates from 1 kBd up to 20 kBd and is LIN 2.0/LIN 2.1/SAE J2602 compliant.

#### 6.7.1 LIN operating modes

#### **6.7.1.1** Active mode

The LIN transceiver will be in Active mode when:

- the SBC is in Normal mode (MC = 10 or 11) and
- the transceiver is enabled (STBCL = 0; see Table 6) and
- the battery voltage (V<sub>BAT</sub>) is above the LIN undervoltage recovery threshold, V<sub>uvr(LIN)</sub>.

In LIN Active mode, the transceiver can transmit and receive data via the LIN bus pin.

The receiver detects data streams on the LIN bus pin (LIN) and transfers them to the microcontroller via pins RXDL (see <u>Figure 1</u>) - LIN recessive is represented by a HIGH level on RXDL, LIN dominant by a LOW level.

The transmit data streams of the protocol controller at the TXDL input are converted by the transmitter into bus signals with optimized slew rate and wave shaping to minimize EME.

#### 6.7.1.2 Lowpower/Off modes

The LIN transceiver will be in Lowpower mode with bus wake-up detection enabled if bit STBCL = 1 (see <u>Table 6</u>). The LIN transceiver can be woken up remotely via pin LIN in Lowpower mode.

When the SBC is in Standby mode or Sleep mode (MC = 00 or 01), the LIN transceiver will be in Off mode if bit STBCL = 0. The LIN transceiver is powered down completely in Off mode to minimize quiescent current consumption.

Filters at the receiver inputs prevent unwanted wake-up events due to automotive transients or EMI.

The wake-up event must remain valid for at least the minimum dominant bus time,  $t_{bus(dom)(min)}$ , for wake-up of the LIN transceiver (see <u>Table 10</u>).

#### 6.7.2 Fail-safe features

#### 6.7.2.1 General fail-safe features

The following fail-safe features have been implemented:

- Pin TXDL has an internal pull-up towards V<sub>V1</sub> to guarantee safe, defined states if these pins are left floating
- The current of the transmitter output stage is limited in order to protect the transmitter against short circuits to pin BAT
- A loss of power (pins BAT and GND) has no impact on the bus lines or on the microcontroller. There will be no reverse currents from the bus.

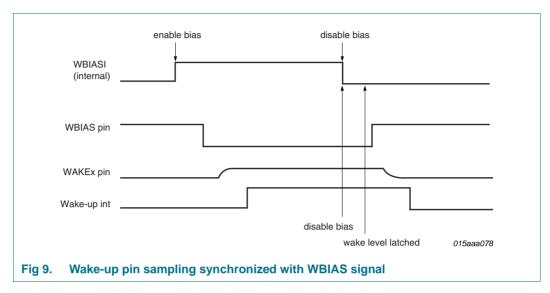
## www.DataSheet4U.cor6.7.2.2 TXDL dominant time-out function

A TXDL dominant time-out timer circuit prevents the bus lines being driven to a permanent dominant state (blocking all network communications) if TXDL is forced permanently LOW by a hardware and/or software application failure. The timer is triggered by a negative edge on the TXDL pin. If the pin remains LOW for longer than the TXDL dominant time-out time ( $t_{to(dom)TXDL}$ ), the transmitter is disabled, driving the bus lines to a recessive state. The timer is reset by a positive edge on the TXDL pin.

#### 6.8 Local wake-up input

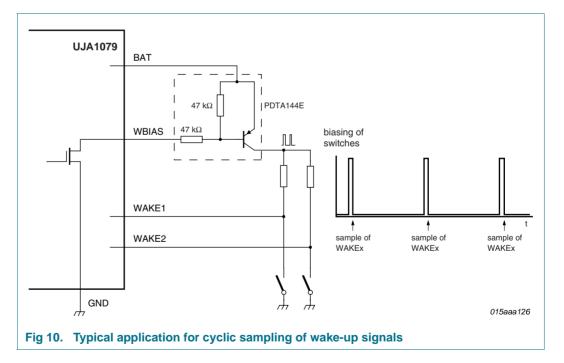
The SBC provides 2 local wake-up pins (WAKE1 and WAKE2). The edge sensitivity (falling, rising or both) of the wake-up pins can be configured independently via the WIC1 and WIC2 bits in the Int\_Control register <a href="Table 6">Table 6</a>). These bits can also be used to disable wake-up via the wake-up pins. When wake-up is enabled, a valid wake-up event on either of these pins will cause a wake-up interrupt to be generated in Standby mode or Normal mode. If the SBC is in Sleep mode when the wake-up event occurs, it will wake up and enter Standby mode. The status of the wake-up pins can be read via the wake-up level status bits (WLS1 and WLS2) in the WD\_and\_Status register (Table 4).

Note that bits WLS1 and WLS2 are only active when at least one of the wake up interrupts is enabled (WIC1  $\neq$  00 or WIC2  $\neq$  00).



The sampling of the wake-up pins can be synchronized with the WBIAS signal by setting bits WSE1 and WSE2 in the Int\_Control register to 1 (if WSEx = 0, wake-up pins are sampled continuously). The sampling will be performed on the rising edge of WBIAS (see Figure 9). The sampling time, 16 ms or 64 ms, is selected via the Wake Bias Control bit (WBC) in the Mode\_Control register.

Figure 10 shows typical circuit for implementing cyclic sampling of the wake-up inputs.



## 6.9 Interrupt output

Pin INTN is an active-LOW, open-drain interrupt output. It is driven LOW when at least one interrupt is pending. An interrupt can be cleared by writing 1 to the corresponding bit in the Int\_Status register (Table 7). Clearing bit LWI in Standby mode only clears the interrupt status bit and not the pending wake-up. The pending wake-up is cleared on entering Normal mode and when the corresponding standby control bit (STBCL) is 0.

On devices that contain a watchdog, the Cyclic Interrupt (CI) is enabled when the watchdog switches to Timeout mode while the SBC is in Standby mode or Normal mode (provided WDOFF = LOW). A CI is generated if the watchdog overflows in Timeout mode.

The CI is provided to alert the microcontroller when the watchdog overflows in Timeout mode. The CI will wake up the microcontroller from a  $\mu C$  standby mode. After polling the Int\_Status register, the microcontroller will be aware that the application is in cyclic wake up mode. It can then perform some checks on LIN before returning to the  $\mu C$  standby mode.

# 6.10 Temperature protection

The temperature of the SBC chip is monitored in Normal and Standby modes. If the temperature is too high, the SBC will go to Overtemp mode, where the RSTN pin is driven LOW and limp home is activated. In addition, the voltage regulator and the LIN transmitter are switched off (see also Section 6.1.6 "Overtemp mode"). When the temperature falls below the temperature shutdown threshold, the SBC will go into the Standby mode. The temperature shutdown threshold is between 165 °C and 200 °C.

# 7. Limiting values

Table 8. Limiting values

www

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_x$	voltage on pin x	DC value				
		pins V1 and INTN		-0.3	7	V
		pins EN, SDI, SDO, SCK, SCSN, TXDL, RXDL, RSTN and WDOFF		-0.3	V <sub>V1</sub> + 0.3	V
		pin VEXCC		$V_{V1}-0.3$	V <sub>V1</sub> + 0.35	V
		pins WAKE1, WAKE2, WBIAS and LIN; with respect to any other pin		-58	+58	V
		pin LIMP and BAT		-0.3	+40	V
		pin VEXCTRL		-0.3	$V_{BAT} + 0.3$	V
		pin DLIN; with respect to any other pin		$V_{BAT}-0.3$	+58	V
I <sub>R(V1-BAT)</sub>	reverse current from pin V1 to pin BAT		[1]	-	25	mΑ
I <sub>DLIN</sub>	current on pin DLIN			-65	0	mΑ
$V_{trt}$	transient voltage	on pins	[2]	-150	+100	V
		BAT: via reverse polarity diode/capacitor				
		LIN: coupling via 1 nF capacitor DLIN: via 1 $k\Omega$ resistor				
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2	[3]			
		pins BAT and LIN; via a series resistor on pins DLIN, WAKE1, WAKE2, LIMP and WBIAS; via transistor on pin VEXCTRL	<u>[4]</u>	-6	+6	kV
		НВМ	<u>[5]</u>			
ataSheet4l	Loom	pins LIN, DLIN, WAKE1 and WAKE2	[6]	-8	+8	kV
alaoneel4t	J.COIII	pin TEST2; referenced to pin BAT		-1.25	+2	kV
		pin TEST2; referenced to other reference pins		-2	+2	kV
		any other pin		-2	+2	kV
		MM	[7]			
		any pin		-300	+300	V
		CDM	[8]			
		corner pins		-750	+750	V
		any other pin		-500	+500	V
Γ <sub>vj</sub>	virtual junction temperature		[9]	-40	+150	°C
T <sub>stg</sub>	storage temperature			-55	+150	°C



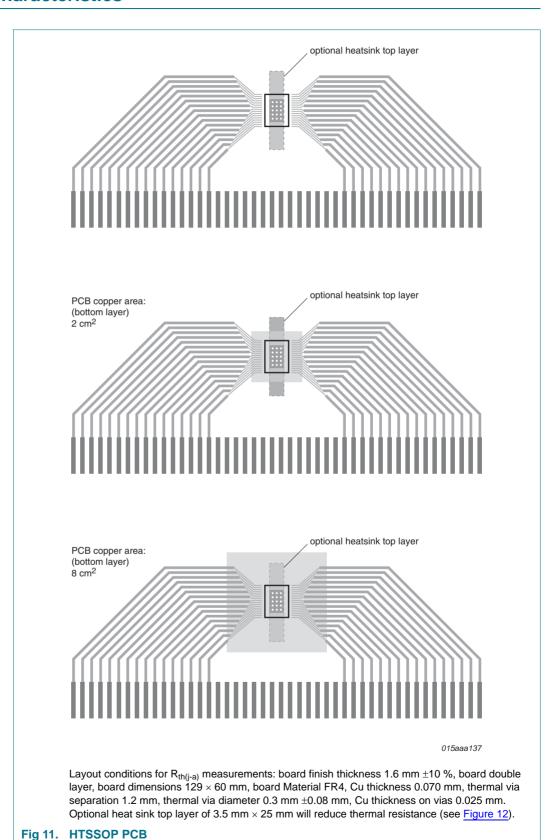
#### Table 8. Limiting values ...continued

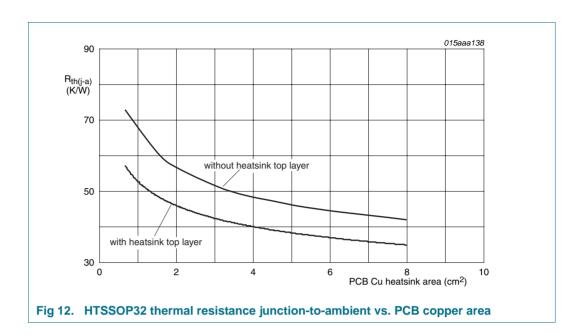
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$T_{amb}$	ambient temperature		-40	+125	°C

- [1] A reverse diode connected between V1 (anode) and BAT (cathode) limits the voltage drop voltage from V1(+) to BAT (-).
- [2] Verified by an external test house to ensure pins can withstand ISO 7637 part 2 automotive transient test pulses 1, 2a, 3a and 3b.
- [3] IEC 61000-4-2 (150 pF. 330 Ω).
- [4] ESD performance according to IEC 61000-4-2 (150 pF, 330 Ω) has been verified by an external test house for pins BAT, LIN, WAKE1 and WAKE2. The result is equal to or better than ±6 kV.
- [5] Human Body Model (HBM): according to AEC-Q100-002 (100 pF, 1.5 k $\Omega$ ).
- [6] V1 and BAT connected to GND, emulating application circuit.
- [7] Machine Model (MM): according to AEC-Q100-003 (200 pF, 0.75  $\mu$ H, 10  $\Omega$ ).
- [8] Charged Device Model (CDM): according to AEC-Q100-011 (field Induced charge; 4 pF).
- [9] In accordance with IEC 60747-1. An alternative definition of virtual junction temperature is:  $T_{vj} = T_{amb} + P \times R_{th(vj-a)}$ , where  $R_{th(vj-a)}$  is a fixed value to be used for the calculation of  $T_{vj}$ . The rating for  $T_{vj}$  limits the allowable combinations of power dissipation (P) and ambient temperature ( $T_{amb}$ ).

# 8. Thermal characteristics





# 9. Static characteristics

Table 9. Static characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Uni
Supply; pin	BAT					
$V_{BAT}$	battery supply voltage		4.5	-	28	V
I <sub>BAT</sub>	battery supply current	MC = 00 (Standby; V1 on) STBCL = 1 (LIN wake-up enabled) WIC1 = WIC2 = 11 (WAKE interrupts enabled); 7.5 V < $V_{BAT}$ < 28 V $I_{V1}$ = 0 mA; $V_{RSTN}$ = $V_{SCSN}$ = $V_{V1}$ $V_{TXDL}$ = $V_{V1}$ ; $V_{SDI}$ = $V_{SCK}$ = 0 V				
		T <sub>vj</sub> = -40 °C	-	75	89	μΑ
		T <sub>vj</sub> = 25 °C	-	68	80	μΑ
		T <sub>vj</sub> = 150 °C	-	62	73	μΑ
		MC = 01 (Sleep; V1 off) STBCL = 1 (LIN wake-up enabled) WIC1 = WIC2 = 11 (WAKE interrupts enabled); $7.5 \text{ V} < \text{V}_{BAT} < 28 \text{ V}$ $\text{V}_{V1} = 0 \text{ V}$				
		$T_{vj} = -40  ^{\circ}C$	-	53	62	μΑ
		T <sub>vj</sub> = 25 °C	-	49	57	μΑ
		$T_{vj} = 150  ^{\circ}C$	-	45	51	μΑ
		contributed by LIN wake-up receiver STBCL = 1 $V_{LIN} = V_{BAT}$ ; 5.5 V < $V_{BAT}$ < 28 V	-	1.1	2	μА
DataSheet4U.	com	contributed by WAKE pin edge detectors; WIC1 = WIC2 = 11 V <sub>WAKE1</sub> = V <sub>WAKE2</sub> = V <sub>BAT</sub>	0	5	10	μА
I <sub>BAT(add)</sub>	additional battery supply	5.1 V < V <sub>BAT</sub> < 7.5 V	-	-	50	μΑ
	current	4.5 V < V <sub>BAT</sub> < 5.1 V V1 on (5 V version)	-	-	3	m <i>P</i>
		LIN Active mode (recessive) STBCL = 0; MC = 1x $V_{TXDL} = V_{V1}$ ; $I_{DLIN} = I_{LIN} = 0$ mA 5.5 V < $V_{BAT}$ < 28 V	-	-	1300	μА
		LIN Active mode (dominant) STBCL = 0; MC = 1x $V_{TXDL} = 0 \text{ V}; I_{DLIN} = I_{LIN} = 0 \text{ mA}$ $V_{BAT} = 14 \text{ V}$	-	-	5	m <i>A</i>
		LIN Active mode (dominant) STBCL = 0; MC = 1x $V_{TXDL}$ = 0 V; $I_{DLIN}$ = $I_{LIN}$ = 0 mA $V_{BAT}$ = 28 V	-	-	10	m/
$V_{th(det)pon}$	power-on detection threshold voltage		4.5	-	5.5	V
$V_{th(det)poff}$	power-off detection threshold voltage		4.25	-	4.5	V
UJA1079_1				© N	XP B.V. 2009. All	rights rese

www



# LIN core system basis chip

Table 9. Static characteristics ... continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>hys(det)pon</sub>	power-on detection hysteresis voltage		200	-	-	mV
$V_{uvd(LIN)}$	LIN undervoltage detection voltage		5	-	5.3	V
$V_{uvr(LIN)}$	LIN undervoltage recovery voltage		5	-	5.5	V
$V_{\text{hys(uvd)LIN}}$	LIN undervoltage detection hysteresis voltage		25	-	300	mV
V <sub>uvd(ctrl)</sub> lext	external current control undervoltage detection voltage		5.9	-	7.5	V
Voltage sou	ırce; pin V1					
Vo	output voltage	$V_{O(V1)nom}$ = 5 V; $V_{BAT}$ = 5.5 V to 28 V $I_{V1}$ = -200 mA to -5 mA; $C_{LIN}$ $\geq$ 560 pF	4.9	5	5.1	V
		$V_{O(V1)nom} = 5 \text{ V}; V_{BAT} = 5.5 \text{ V} \text{ to } 28 \text{ V}$ $I_{V1} = -200 \text{ mA to } -5 \text{ mA}; C_{LIN} \ge 220 \text{ pF}$	4.85	5	5.15	V
		$V_{O(V1)nom} = 5 \text{ V}; V_{BAT} = 5.5 \text{ V} \text{ to } 28 \text{ V}$ $I_{V1} = -250 \text{ mA} \text{ to } -200 \text{ mA}$	4.75	5	5.1	V
		$V_{O(V1)nom} = 5 \text{ V}; V_{BAT} = 5.5 \text{ V} \text{ to } 5.75 \text{ V}$ $I_{V1} = -250 \text{ mA to } -5 \text{ mA}$ $150 \text{ °C} < T_{vi} < 200 \text{ °C}$	4.5	5	5.1	V
		$V_{O(V1)nom} = 5 \text{ V}; V_{BAT} = 5.75 \text{ V} \text{ to } 28 \text{ V}$ $I_{V1} = -250 \text{ mA to } -5 \text{ mA}$ $150 \text{ °C} < T_{vj} < 200 \text{ °C}$	4.85	5	5.1	V
DataSheet4U.c	com	$V_{O(V1)nom} = 3.3 \text{ V}; V_{BAT} = 4.5 \text{ V to } 28 \text{ V}$ $I_{V1} = -250 \text{ mA to } -5 \text{ mA}; C_{LIN} \ge 560 \text{ pF}$	3.234	3.3	3.366	V
		$V_{O(V1)nom} = 3.3 \text{ V}; V_{BAT} = 4.5 \text{ V to } 28 \text{ V}$ $I_{V1} = -250 \text{ mA to } -5 \text{ mA}; C_{LIN} \ge 220 \text{ pF}$	3.201	3.3	3.399	V
		$V_{O(V1)nom} = 3.3 \text{ V}; V_{BAT} = 4.5 \text{ V} \text{ to } 28 \text{ V}$ $I_{V1} = -250 \text{ mA to } -5 \text{ mA}$ $150 \text{ °C} < T_{vj} < 200 \text{ °C}$	2.97	3.3	3.366	V
R <sub>(BAT-V1)</sub>	resistance between pin BAT and pin V1	$V_{O(V1)nom} = 5 \text{ V}; V_{BAT} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$ $I_{V1} = -250 \text{ mA} \text{ to } -5 \text{ mA}$	-	-	3	Ω
V <sub>uvd</sub>	undervoltage detection	90 %; V <sub>O(V1)nom</sub> = 5 V; RTHC = 0	4.5	-	4.75	V
	voltage	90 %; V <sub>O(V1)nom</sub> = 3.3 V; RTHC = 0	2.97	-	3.135	V
		70 %; V <sub>O(V1)nom</sub> = 5 V; RTHC = 1	3.5	-	3.75	V
$V_{uvr}$	undervoltage recovery	90 %; V <sub>O(V1)nom</sub> = 5 V; RTHC = 0	4.56	-	4.9	V
	voltage	90 %; V <sub>O(V1)nom</sub> = 3.3 V; RTHC = 0	3.025	-	3.234	V
		70 %; V <sub>O(V1)nom</sub> = 5 V; RTHC = 1	3.56	-	4	V
$I_{O(sc)}$	short-circuit output current	I <sub>VEXCC</sub> = 0 mA	-600	-	-250	mA



Table 9. Static characteristics ... continued

Symbol	Parameter	Conditions	Min	Тур	Max	U
Load regulat	tion					
$\Delta V_{V1}$	voltage variation on pin V1	as a function of load current variation $V_{BAT} = 5.75 \text{ V}$ to 28 V $I_{V1} = -250 \text{ mA}$ to $-5 \text{ mA}$	-	-	25	m
Line regulati	ion					
$\Delta V_{V1}$	voltage variation on pin V1	as a function of supply voltage variation $V_{BAT} = 5.5 \text{ V}$ to 28 V; $I_{V1} = -30 \text{ mA}$	-	-	25	m
PNP base;	pin VEXCTRL					
$I_{O(sc)}$	short-circuit output current	$V_{VEXCTRL} \ge 4.5 \text{ V}; V_{BAT} = 6 \text{ V to } 28 \text{ V}$	3.5	5.8	8	m
I <sub>th(act)PNP</sub>	PNP activation threshold current	load current increasing; external PNP transistor connected - see Section 6.6.2				
		PDC 0	74	130	191	n
		PDC 0; T <sub>vj</sub> = 150 °C	74	85	99	n
		PDC 1	44	76	114	n
		PDC 1; T <sub>vj</sub> = 150 °C	44	50	59	n
I <sub>th(deact)</sub> PNP	PNP deactivation threshold current	load current falling; external PNP transistor connected - see Section 6.6.2				
		PDC 0	40	76	120	n
		PDC 0; T <sub>vj</sub> = 150 °C	44	50	59	n
		PDC 1	11	22	36	n
DND celles	tor; pin VEXCC	PDC 1; T <sub>vj</sub> = 150 °C	12	15	18	n
V <sub>th(act)</sub> IIim DataSheet4U.c	current limiting activation threshold voltage	measured across resistor connected between pins VEXCC and V1 (see Section 6.6.2) $2.97 \text{ V} \le \text{V}_{\text{V1}} \le 5.5 \text{ V}$ ; 6 V < V <sub>BAT</sub> < 28 V	240	-	330	n
Serial perip	heral interface inputs; pins SD	DI. SCK and SCSN				
V <sub>th(sw)</sub>	switching threshold voltage	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	0.3V <sub>V1</sub>	-	0.7V <sub>V1</sub>	\
V <sub>hys(i)</sub>	input hysteresis voltage	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	100	-	900	n
R <sub>pd(SCK)</sub>	pull-down resistance on pin SCK		50	130	400	k
$R_{pu(SCSN)}$	pull-up resistance on pin SCSN		50	130	400	k
I <sub>LI(SDI)</sub>	input leakage current on pin SDI		<b>-</b> 5	-	+5	μ
Serial perip	heral interface data output; pi	n SDO				
I <sub>OH</sub>	HIGH-level output current	$V_{SCSN} = 0 \text{ V}; V_O = V_{V1} - 0.4 \text{ V}$ $V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	-30	-	-1.6	n
l <sub>OL</sub>	LOW-level output current	$V_{SCSN} = 0 \text{ V}; V_O = 0.4 \text{ V}$ $V_{V1} = 2.97 \text{ V} \text{ to } 5.5 \text{ V}$	1.6	-	30	n
02		1 1 2.0. 1 10 0.0 1				



Table 9. Static characteristics ... continued

Symbol	Parameter	Conditions	Min	Тур	Max	ι
Reset outp	ut with clamping detection; pin	RSTN				
I <sub>OH</sub>	HIGH-level output current	$V_{RSTN} = 0.8V_{V1}$ $V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	-1500	-	-100	μ
I <sub>OL</sub>	LOW-level output current	strong; $V_{RSTN} = 0.2V_{V1}$ $V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$ $-40 \text{ °C} < T_{vj} < 200 \text{ °C}$	4.9	-	40	n
		weak; $V_{RSTN} = 0.8V_{V1}$ $V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$ $-40 \text{ °C} < T_{vj} < 200 \text{ °C}$	200	-	540	Ļ
V <sub>OL</sub>	LOW-level output voltage	$\begin{split} &V_{V1}=1~V~to~5.5~V\\ &pull\text{-up resistor to}~V_{V1}\geq 900~\Omega\\ &-40~^{\circ}\text{C}~<\text{T}_{vj}<200~^{\circ}\text{C};~V_{BAT}<28~V\\ &I_{R(V1\text{-BAT})}<25~\text{mA} \end{split}$	0	-	0.2V <sub>V1</sub>	١
		$V_{V1}$ = 2.975 V to 5.5 V pull-up resistor to V1 ≥ 900 Ω –40 °C < $T_{vj}$ < 200 °C	0	-	0.5	١
V <sub>OH</sub>	HIGH-level output voltage	-40 °C < T <sub>vj</sub> < 200 °C	0.8V <sub>V1</sub>	-	V <sub>V1</sub> + 0.3	١
V <sub>th(sw)</sub>	switching threshold voltage	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	0.3V <sub>V1</sub>	-	0.7V <sub>V1</sub>	١
V <sub>hys(i)</sub>	input hysteresis voltage	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	100	-	900	r
	utput; pin INTN					
l <sub>OL</sub>	LOW-level output current	V <sub>OL</sub> = 0.4 V	1.6	-	15	r
Enable out	put; pin EN					
I <sub>OH</sub>	HIGH-level output current	$V_{OH} = V_{V1} - 0.4 V$ $V_{V1} = 2.97 V \text{ to } 5.5 V$	-20	-	-1.6	r
SlaSheet4U.	conLOW-level output current	$V_{OL} = 0.4 \text{ V}; V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	1.6	-	20	r
$V_{OL}$	LOW-level output voltage	$I_{OL}$ = 20 $\mu$ A; $V_{V1}$ = 1.5 $V$	-	-	0.4	١
Watchdog	off input; pin WDOFF					
$V_{th(sw)}$	switching threshold voltage	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	$0.3V_{V1}$	-	$0.7V_{V1}$	١
$V_{hys(i)}$	input hysteresis voltage	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	100	-	900	r
R <sub>pupd</sub>	pull-up/pull-down resistance	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	5	10	20	k
Wake input	; pin WAKE1, WAKE2					
$V_{th(sw)}$	switching threshold voltage		2	-	3.75	١
$V_{hys(i)}$	input hysteresis voltage		100	-	1000	r
<b>I</b> <sub>pu</sub>	pull-up current	$V_{WAKE} = 0 V \text{ for } t < t_{wake}$	-2	-	0	ļ
$I_{pd}$	pull-down current	$V_{WAKE} = V_{BAT}$ for $t < t_{wake}$	0	-	2	ļ
Limp home	output; pin LIMP					
lo	output current	$V_{LIMP}$ = 0.4 V; LHWC = LHC = 1 $T_{vj}$ = -40 °C to 200 °C	8.0	-	8	r
Wake bias	output; pin WBIAS					
I <sub>O</sub>	output current	$V_{WBIAS} = 1.4 V$	1	-	7	r
LIN transm	it data input; pin TXDL					
$V_{th(sw)}$	switching threshold voltage	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	0.3V <sub>V1</sub>	-	$0.7V_{V1}$	\

www



# LIN core system basis chip

Table 9. Static characteristics ... continued

Symbol	Parameter	Conditions	Min	Тур	Max	Uni
$V_{hys(i)}$	input hysteresis voltage	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$	100	-	900	mV
R <sub>pu</sub>	pull-up resistance		4	12	25	kΩ
LIN receive d	ata output; pin RXDL					
I <sub>ОН</sub>	HIGH-level output current	LIN Active mode; $V_{RXDL} = V_{V1} - 0.4 \text{ V}$	-20	-	-1.5	mΑ
l <sub>OL</sub>	LOW-level output current	V <sub>RXDL</sub> = 0.4 V	1.6	-	20	mΑ
R <sub>pu</sub>	pull-up resistance	MC = 00; Standby mode	4	12	25	kΩ
LIN bus line;	pin LIN					
I <sub>BUS_LIM</sub>	current limitation for driver dominant state	LIN Active mode; $V_{BAT} = V_{LIN} = 18 \text{ V}$ $V_{TXDL} = 0 \text{ V}$	40	-	100	mA
BUS_PAS_rec	receiver recessive input leakage current	$V_{LIN} = 28 \text{ V}; V_{BAT} = 5.5 \text{ V}; V_{TXDL} = V_{V1}$	-	-	2	μА
I <sub>BUS_PAS_dom</sub>	receiver dominant input leakage current including pull-up resistor	$V_{TXDL} = V_{V1}$ ; $V_{LIN} = 0$ V; $V_{BAT} = 14$ V	-10	-	+10	μА
$I_{L(log)}$	loss of ground leakage current	$V_{BAT} = V_{GND} = 28 \text{ V}; V_{LIN} = 0 \text{ V}$	-100	-	10	μА
$I_{L(lob)}$	loss of battery leakage current	$V_{BAT} = 0 \text{ V}; V_{LIN} = 28 \text{ V}$	-	-	2	μΑ
V <sub>rec(RX)</sub>	receiver recessive voltage	$V_{BAT} = 5.5 \text{ V to } 18 \text{ V}$	$0.6 \times V_{BAT}$	-	-	V
$V_{dom(RX)}$	receiver dominant voltage	V <sub>BAT</sub> = 5.5 V to 18 V	-	-	$0.4V_{BAT}$	V
V <sub>th(cntr)</sub> RX	receiver center threshold voltage	$V_{th(cntr)RX} = (V_{th(rec)RX} + V_{th(dom)RX})/2$ $V_{BAT} = 5.5 \text{ V to } 18 \text{ V}$ LIN Active/Lowpower modes	$\begin{array}{c} 0.475 \\ \times \ V_{BAT} \end{array}$	$\begin{array}{c} 0.5 \times \\ V_{BAT} \end{array}$	$0.525 \times V_{BAT}$	V
Vth(hys)RX DataSheet4U.co	receiver hysteresis threshold voltage	$V_{th(hys)RX} = V_{th(rec)RX} - V_{th(dom)RX}$ $V_{BAT} = 5.5 \text{ V to } 18 \text{ V}$ LIN Active/Lowpower modes	$0.05 \times V_{BAT}$	$0.15 \times V_{BAT}$	0.175 × V <sub>BAT</sub>	V
C <sub>ext</sub>	external capacitance	on pin LIN	-	-	30	pF
$V_{O(dom)}$	dominant output voltage	LIN Active mode; $V_{TXDL} = 0 \text{ V}$ $V_{BAT} = 7 \text{ V}$	-	-	1.4	V
		LIN Active mode; $V_{TXDL} = 0 \text{ V}$ $V_{BAT} = 18 \text{ V}$	-	-	2.0	V
LIN bus term	ination; pin DLIN					
$\Delta V_{(DLIN-BAT)}$	voltage difference between pin DLIN and pin BAT	5 mA < I <sub>DLIN</sub> < 20 mA	0.4	0.65	1	V
Temperature	protection					
T <sub>th(act)otp</sub>	overtemperature protection activation threshold temperature		165	180	200	°C
T <sub>th(rel)otp</sub>	overtemperature protection release threshold temperature		126	138	150	°C

# 10. Dynamic characteristics

## Table 10. Dynamic characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Uni
Voltage source	; pin V1						
t <sub>d(uvd)</sub>	undervoltage detection delay time	$V_{V1}$ falling; $dV_{V1}/dt = 0.1 \text{ V/}\mu\text{s}$		7	-	23	μS
t <sub>det(CL)L</sub>	LOW-level clamping detection time	$V_{V1}$ < 0.9 $V_{O(V1)nom}$ ; V1 active		95	-	140	ms
Serial periphera	al interface timing; pins SCSN	I, SCK, SDI and SDO					
t <sub>cy(clk)</sub>	clock cycle time	V <sub>V1</sub> = 2.97 V to 5.5 V		320	-	-	ns
t <sub>SPILEAD</sub>	SPI enable lead time	$V_{V1}$ = 2.97 V to 5.5 V; clock is LOW when SPI select falls		110	-	-	ns
t <sub>SPILAG</sub>	SPI enable lag time	$V_{V1}$ = 2.97 V to 5.5 V; clock is LOW when SPI select rises		140	-	-	ns
t <sub>clk(H)</sub>	clock HIGH time	V <sub>V1</sub> = 2.97 V to 5.5 V		160	-	-	ns
t <sub>clk(L)</sub>	clock LOW time	V <sub>V1</sub> = 2.97 V to 5.5 V		160	-	-	ns
t <sub>su(D)</sub>	data input set-up time	V <sub>V1</sub> = 2.97 V to 5.5 V		0	-	-	ns
t <sub>h(D)</sub>	data input hold time	$V_{V1} = 2.97 \text{ V to } 5.5 \text{ V}$		80	-	-	ns
$t_{V(Q)}$	data output valid time	pin SDO; $V_{V1}$ = 2.97 V to 5.5 V $C_L$ = 100 pF		-	-	110	ns
t <sub>WH(S)</sub>	chip select pulse width HIGH	V <sub>V1</sub> = 2.97 V to 5.5 V		20	-	-	ns
Reset output; p	in RSTN						
t <sub>w(rst)</sub>	reset pulse width	long; $I_{pu(RSTN)}$ < 100 $\mu$ A; no pull-up		20	-	25	ms
		short; $R_{pu(RSTN)} = 900 \Omega$ to 1100 $\Omega$		3.6	-	5	ms
det Chiet4U.com	HIGH-level clamping detection time	RSTN driven HIGH internally but RSTN remains LOW		95	-	140	ms
t <sub>fltr</sub>	filter time			7	-	18	μS
Watchdog off ir	nput; pin WDOFF						
t <sub>fltr</sub>	filter time			0.9	-	2.3	ms
Wake input; pin	WAKE1, WAKE2						
t <sub>wake</sub>	wake-up time			10	-	40	μS
t <sub>d(po)</sub>	power-on delay time			113	-	278	μS
LIN transceiver	; pins LIN, TXDL, RXDL						
δ1	duty cycle 1	$\begin{split} &V_{th(rec)RX(max)} = 0.744 V_{BAT} \\ &V_{th(dom)RX(max)} = 0.581 V_{BAT}; t_{bit} = 50 \ \mu s \\ &V_{BAT} = 7 \ V \ to \ 18 \ V; \ LSC = 0 \end{split}$	[1] [2]	0.396	-	-	
		$\begin{split} &V_{th(rec)RX(max)} = 0.76 V_{BAT} \\ &V_{th(dom)RX(max)} = 0.593 V_{BAT};  t_{bit} = 50  \mu s \\ &V_{BAT} = 5.5  V  to  7  V;  LSC = 0 \end{split}$	[1] [2]	0.396	-	-	



Table 10. Dynamic characteristics ...continued

 $T_{vj}$  = -40 °C to +150 °C;  $V_{BAT}$  = 4.5 V to 28 V;  $V_{BAT}$  >  $V_{V1}$ ;  $R_{LIN}$  = 500  $\Omega$ ; all voltages are defined with respect to ground; positive currents flow in the IC; typical values are given at  $V_{BAT}$  = 14 V; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
δ2	duty cycle 2	$\begin{split} &V_{th(rec)RX(min)} = 0.422 V_{BAT} \\ &V_{th(dom)RX(min)} = 0.284 V_{BAT;}  t_{bit} = 50  \mu s \\ &V_{BAT} = 7.6  V  to  18  V;  LSC = 0 \end{split}$	[2] [3]	-	-	0.581	
		$\begin{split} &V_{th(rec)RX(min)} = 0.41 V_{BAT} \\ &V_{th(dom)RX(min)} = 0.275 V_{BAT};  t_{bit} = 50  \mu s \\ &V_{BAT} = 6.1  V  to  7.6  V;  LSC = 0 \end{split}$	[2] [3]	-	-	0.581	
δ3	duty cycle 3	$\begin{split} &V_{th(rec)RX(max)} = 0.778V_{BAT} \\ &V_{th(dom)RX(max)} = 0.616V_{BAT} \\ &t_{bit} = 96~\mu s;~V_{BAT} = 7~V~to~18~V \\ &LSC = 1 \end{split}$	[1] [2]	0.417	-	-	
		$\begin{split} &V_{th(rec)RX(max)} = 0.797 V_{BAT} \\ &V_{th(dom)RX(max)} = 0.630 V_{BAT} \\ &t_{bit} = 96~\mu s;~V_{BAT} = 5.5~V~to~7~V \\ &LSC = 1 \end{split}$	[1] [2]	0.417	-	-	
δ4	duty cycle 4	$\begin{split} &V_{th(rec)RX(min)} = 0.389 V_{BAT} \\ &V_{th(dom)RX(min)} = 0.251 V_{BAT;}  t_{bit} = 96  \mu s \\ &V_{BAT} = 7.6  V  to  18  V;  LSC = 1 \end{split}$	[2] [3]	-	-	0.590	
		$\begin{split} &V_{th(rec)RX(min)} = 0.378V_{BAT} \\ &V_{th(dom)RX(min)} = 0.242V_{BAT};  t_{bit} = 96  \mu s \\ &V_{BAT} = 6.1  V  to  7.6  V;  LSC = 1 \end{split}$	[2] [3]	-	-	0.590	
$t_{PD(RX)r}$	rising receiver propagation delay	$V_{BAT}$ = 5.5 V to 18 V; $R_{RXDL}$ = 2.4 k $\Omega$ $C_{RXDL}$ = 20 pF		-	-	6	μS
$t_{\text{PD}(\text{RX})f}$	falling receiver propagation delay	$V_{BAT}$ = 5.5 V to 18 V; $R_{RXDL}$ = 2.4 k $\Omega$ $C_{RXDL}$ = 20 pF		-	-	6	μS
t <sub>PD(RX)sym</sub>	receiver propagation delay symmetry	$V_{BAT}$ = 5.5 V to 18 V; $R_{RXDL}$ = 2.4 k $\Omega$ $C_{RXDL}$ = 20 pF	[4]	-2	-	+2	μS
t <sub>bus(dom)(min)</sub>	minimum dominant bus time	for wake-up of the LIN transceiver		28	-	104	μS
DataSheet4U.com to(dom)TXDL	TXDL dominant time-out time	LIN online mode; $V_{TXDL} = 0 V$		20	-	80	ms
Wake bias outp	ut; pin WBIAS						
t <sub>WBIASL</sub>	WBIAS LOW time			227	-	278	μS
t <sub>cy</sub>	cycle time	WBC = 1		58.1	-	71.2	ms
		WBC = 0		14.5	-	17.8	ms
Watchdog							
$t_{trig(wd)1}$	watchdog trigger time 1	Normal mode watchdog Window mode only	[5]	0.45 × NWP[6]	-	0.555 × NWP[6]	ms
$t_{\text{trig(wd)2}}$	watchdog trigger time 2	Normal, Standby and Sleep modes watchdog Window mode only	[7]	0.9 × NWP[6]	-	1.11 × NWP[6]	ms
Oscillator							
f <sub>osc</sub>	oscillator frequency			460.8	512	563.2	kHz

$$[1] \quad \delta I, \, \delta \mathcal{I} \, = \, \frac{t_{bus(rec)(min)}}{2 \times t_{bit}} \, .$$

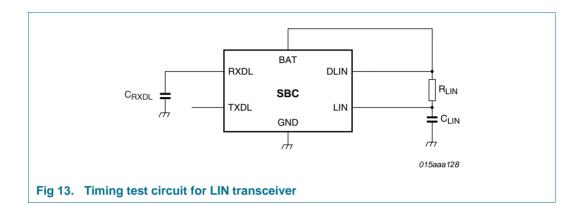
[2] Bus load conditions are:  $C_L$  = 1 nF and  $R_L$  = 1 k $\Omega$ ;  $C_L$  = 6.8 nF and  $R_L$  = 660  $\Omega$ ;  $C_L$  = 10 nF and  $R_L$  = 500  $\Omega$ .

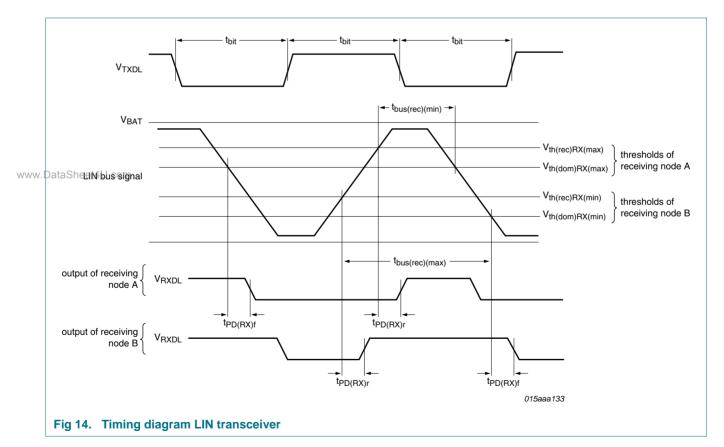
$$[3] \quad \delta 2, \, \delta 4 \, = \, \frac{t_{bus(rec)(max)}}{2 \times t_{bit}} \, .$$

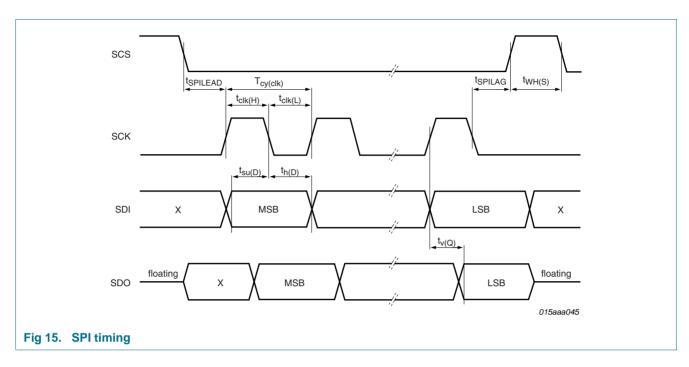
UJA1079\_1 © NXP B.V. 2009. All rights reserved.



- [4]  $t_{PD(RX)sym} = t_{PD(RX)r} t_{PD(RX)f}$ .
- [5] A system reset will be performed if the watchdog is in Window mode and is triggered less than t<sub>trig(wd)1</sub> after the start of the watchdog period (or in the first half of the watchdog period).
- [6] The nominal watchdog period is programmed via the NWP control bits in the WD\_and\_Status register (see <u>Table 4</u>); valid in watchdog Window mode only.
- [7] The watchdog will be reset if it is in window mode and is triggered at least t<sub>trig(wd)1</sub>, but not more than t<sub>trig(wd)2</sub>, after the start of the watchdog period (or in the second half of the watchdog period). A system reset will be performed if the watchdog is triggered more than t<sub>trig(wd)2</sub> after the start of the watchdog period (watchdog overflows).







# 11. Test information

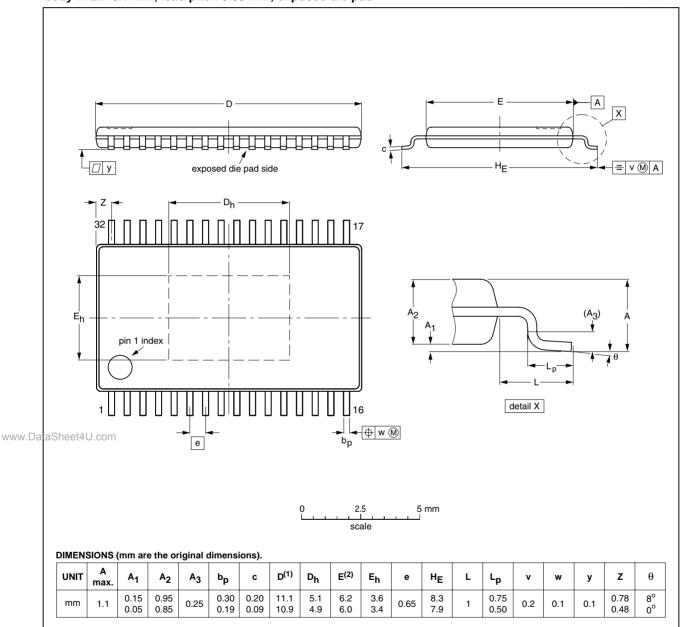
# 11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q100 - Failure mechanism based stress test qualification for integrated circuits*, and is suitable for use in automotive applications.

# 12. Package outline

HTSSOP32: plastic thermal enhanced thin shrink small outline package; 32 leads; body width 6.1 mm; lead pitch 0.65 mm; exposed die pad

SOT549-1



#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT549-1		MO-153			<del>-03-04-07</del> 05-11-02

Fig 16. Package outline SOT549-1 (HTSSOP32)

JJA1079\_1 © NXP B.V. 2009. All rights reserved.

# 13. Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365* "Surface mount reflow soldering description".

# 13.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

## 13.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- · Board specifications, including the board finish, solder masks and vias
- Package footprints, including solder thieves and orientation
- The moisture sensitivity level of the packages
- Package placement
- Inspection and repair
- Lead-free soldering versus SnPb soldering

# 13.3 Wave soldering

Key characteristics in wave soldering are:

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- Solder bath specifications, including temperature and impurities

www.DataSheet4U.com

UJA1079\_1 © NXP B.V. 2009. All rights reserved.

40 of 44

LIN core system basis chip

## 13.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 17</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with Table 11 and 12

Table 11. SnPb eutectic process (from J-STD-020C)

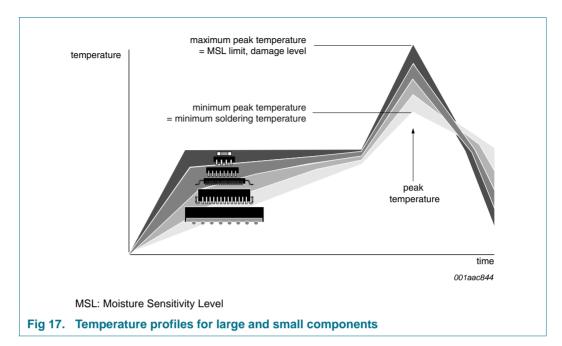
Package thickness (mm)	Package reflow temperature (°C)			
	Volume (mm³)			
	< 350	≥ 350		
< 2.5	235	220		
≥ 2.5	220	220		

Table 12. Lead-free process (from J-STD-020C)

Package thickness (mm)	Package reflow temperature (°C)					
	Volume (mm³)					
	< 350	350 to 2000	> 2000			
< 1.6	260	260	260			
1.6 to 2.5	260	250	245			
> 2.5	250	245	245			

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 17.



For further information on temperature profiles, refer to Application Note *AN10365* "Surface mount reflow soldering description".



# 14. Revision history

# Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
UJA1079_1	20091201	Product data sheet	-	-

# 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

#### 15.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

#### 15.3 Disclaimers

**General** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information, and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental

damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

#### 15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 16. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

UJA1079\_1 © NXP B.V. 2009. All rights reserved.



# 17. Contents

1	General description
2	Features
2.1	General
2.2	LIN transceiver
2.3	Power management 2
2.4	Control and Diagnostic features 2
2.5	Voltage regulator V1
3	Ordering information 3
4	Block diagram 4
5	Pinning information 5
5.1	Pinning
5.2	Pin description 5
6	Functional description 6
6.1	System Controller 6
6.1.1	Introduction
6.1.2	Off mode 9
6.1.3	Standby mode 9
6.1.4	Normal mode 9
6.1.5	Sleep mode
6.1.6	Overtemp mode
6.2	SPI
6.2.1	Introduction
6.2.2	Register map
6.2.3	WD_and_Status register
6.2.4	Mode_Control register
6.2.5	Int_Control register
6.2.6	Int_Status register
6.3	On-chip oscillator
6.4	Watchdog (UJA1079/xx/WD versions) 16
6.4.1	Watchdog Window behavior
6.4.2	Watchdog Timeout behavior
	et4Watchdog Off behavior
6.5	System reset
6.5.1	RSTN pin
6.5.2	EN output
6.5.3	LIMP output
6.6	Power supplies
6.6.1	Battery pin (BAT)
6.6.2	Voltage regulator V1
6.7	LIN transceiver
6.7.1	LIN operating modes
6.7.1.1	Lowpower/Off modes
6.7.1.2 6.7.2	Fail-safe features
6.7.2 6.7.2.1	General fail-safe features
6.7.2.1	TXDL dominant time-out function
6.8	Local wake-up input
0.0	Local wake-up iliput

6.9	Interrupt output	24
6.10	Temperature protection	24
7	Limiting values	25
8	Thermal characteristics	27
9	Static characteristics	29
10	Dynamic characteristics	34
11	Test information	37
11.1	Quality information	37
12	Package outline	38
13	Soldering of SMD packages	39
13.1	Introduction to soldering	39
13.2	Wave and reflow soldering	39
13.3	Wave soldering	39
13.4	Reflow soldering	40
14	Revision history	42
15	Legal information	43
15.1	Data sheet status	43
15.2	Definitions	43
15.3	Disclaimers	43
15.4	Trademarks	43
16	Contact information	43
17	Contents	44

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.





© NXP B.V. 2009. All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 1 December 2009 Document identifier: UJA1079\_1